



## MMDT2227

Preliminary

DUAL TRANSISTOR

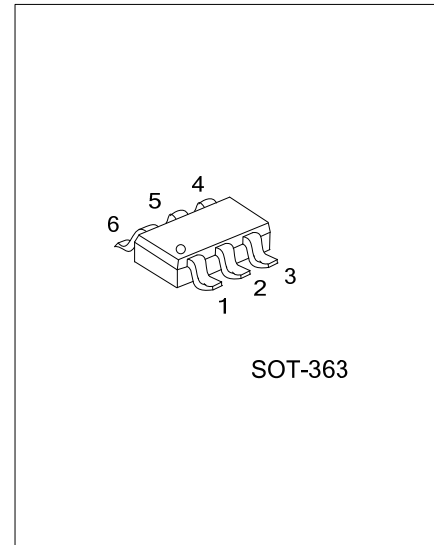
### NPN & PNP GENERAL PURPOSE AMPLIFIER

#### DESCRIPTION

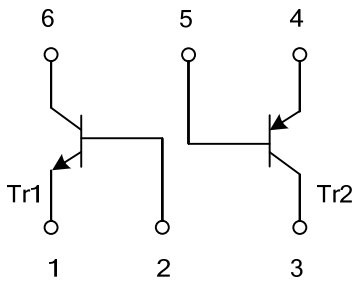
The UTC **MMDT2227** is an NPN & PNP general purpose amplifier. it's suitable for a medium power amplifier and switch requiring collector currents up to 500mA.

#### FEATURES

- \* Low  $V_{CE(SAT)}$ ,  $V_{CE(SAT)}=0.4V$  (typ.) @  $I_C / I_B=150mA/15mA$ ,  
 $V_{CE(SAT)}=1.4V$  (typ.) @  $I_C / I_B = 300mA/30mA$
- \* High collector current gain under high collector current condition



#### EQUIVALENT CIRCUIT

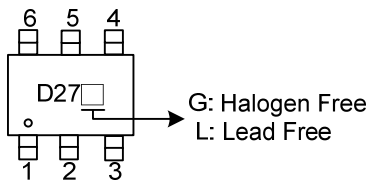


#### ORDERING INFORMATION

Ordering Number		Package	Pin Assignment						Packing
Lead Free	Halogen Free		1	2	3	4	5	6	
MMDT2227L-AL6-R	MMDT2227G-AL6-R	SOT-363	E1	B1	C2	E2	B2	C1	Tape Reel

<p>MMDT2227L-AL6-R</p> <ul style="list-style-type: none"> <li>(1) Packing Type</li> <li>(2) Package Type</li> <li>(3) Halogen Free</li> </ul>	<ul style="list-style-type: none"> <li>(1) R: Tape Reel</li> <li>(2) AL6: SOT-363</li> <li>(3) Halogen Free, L: Lead Free</li> </ul>
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#### MARKING



■ ABSOLUTE MAXIMUM RATINGS\* (T<sub>A</sub>=25°C, unless otherwise specified)(Note 2)

PARAMETER	SYMBOL	RATINGS		UNIT
		TR1	TR2	
Collector-Emitter Voltage	V <sub>CEO</sub>	30	-30	V
Collector-Base Voltage	V <sub>CBO</sub>	60	-60	V
Emitter-Base Voltage	V <sub>EBO</sub>	5.0	-5.0	V
Collector Current - Continuous	I <sub>C</sub>	500	-500	mA
Total Device Dissipation	P <sub>D</sub>	300		mW
Derate above 25°C		2.4		mW/°C
Junction Temperature	T <sub>J</sub>	+150		°C
Storage Temperature	T <sub>STG</sub>	-55 ~ +150		°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

■ THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Case	θ <sub>JC</sub>	415	°C/W

■ ELECTRICAL CHARACTERISTICS (T<sub>A</sub>=25°C unless otherwise specified)

TR1

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>OFF CHARACTERISTICS</b>						
Collector-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	I <sub>C</sub> =10mA, I <sub>B</sub> =0 (Note)	30			V
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	I <sub>C</sub> =10 μA, I <sub>E</sub> =0	60			V
Emitter-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> =10μA, I <sub>C</sub> =0	5.0			V
Collector Cutoff Current	I <sub>CBO</sub>	V <sub>CB</sub> = 50V, I <sub>E</sub> =0			30	nA
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> =3.0V, I <sub>C</sub> =0			30	nA
<b>ON CHARACTERISTICS</b>						
DC Current Gain	h <sub>FE</sub>	I <sub>C</sub> =1.0mA, V <sub>CE</sub> =10V	50			
		I <sub>C</sub> =10mA, V <sub>CE</sub> =10V	75			
		I <sub>C</sub> =150mA, V <sub>CE</sub> = 1 V (Note)	100			
		I <sub>C</sub> =300mA, V <sub>CE</sub> =10V (Note)	30			
Collector-Emitter Saturation Voltage (Note)	V <sub>CE(SAT)</sub>	I <sub>C</sub> =150mA, I <sub>B</sub> =15mA			0.4	V
		I <sub>C</sub> =300mA, I <sub>B</sub> =30mA			1.4	V
Base-Emitter Saturation Voltage (Note)	V <sub>BE(SAT)</sub>	I <sub>C</sub> =150mA, I <sub>B</sub> =15mA			1.3	V
<b>SMALL SIGNAL CHARACTERISTICS</b>						
Current Gain - Bandwidth Product	f <sub>T</sub>	I <sub>C</sub> = 50mA, V <sub>CE</sub> =20V, f =100MHz		250		MHz
Output Capacitance	C <sub>OBO</sub>	V <sub>CB</sub> =10 V, I <sub>E</sub> =0, f=100 kHz		4.0		pF
Input Capacitance	C <sub>IBO</sub>	V <sub>EB</sub> =2.0V, I <sub>C</sub> =0, f=100 kHz		12		pF
Noise Figure	NF	I <sub>C</sub> =100μA, V <sub>CE</sub> =10V, R <sub>S</sub> =1.0kΩ, f =1.0kHz		2.0		dB

Note: Pulse Test: Pulse Width ≤ 300μs, Duty Cycle ≤ 2.0%

■ ELECTRICAL CHARACTERISTICS ( $T_A=25^\circ\text{C}$  unless otherwise specified)

## TR2

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>OFF CHARACTERISTICS</b>						
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=-10\text{mA}, I_B=0$ (Note)	-30			V
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=-10\ \mu\text{A}, I_E=0$	-60			V
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=-10\ \mu\text{A}, I_C=0$	-5.0			V
Collector Cutoff Current	$I_{CBO}$	$V_{CB}=-50\text{V}, I_E=0$			-30	nA
Emitter Cutoff Current	$I_{EBO}$	$V_{EB}=-3.0\text{V}, I_C=0$			-30	nA
<b>ON CHARACTERISTICS</b>						
DC Current Gain	$h_{FE}$	$I_C=-1.0\text{mA}, V_{CE}=-10\text{V}$	-50			
		$I_C=-10\text{mA}, V_{CE}=-10\text{V}$	-75			
		$I_C=-150\text{mA}, V_{CE}=-1\text{V}$ (Note)	-100			
		$I_C=-300\text{mA}, V_{CE}=-10\text{V}$ (Note)	-30			
Collector-Emitter Saturation Voltage (Note)	$V_{CE(SAT)}$	$I_C=-150\text{mA}, I_B=-15\text{mA}$			-0.4	V
		$I_C=-300\text{mA}, I_B=-30\text{mA}$			-1.4	V
Base-Emitter Saturation Voltage (Note)	$V_{BE(SAT)}$	$I_C=-150\text{mA}, I_B=-15\text{mA}$			-1.3	V
<b>SMALL SIGNAL CHARACTERISTICS</b>						
Current Gain - Bandwidth Product	$f_T$	$I_C=-50\text{mA}, V_{CE}=-20\text{V}, f=100\text{MHz}$		250		MHz
Output Capacitance	$C_{OBO}$	$V_{CB}=-10\text{V}, I_E=0, f=100\text{kHz}$		4.0		pF
Input Capacitance	$C_{IBO}$	$V_{EB}=-2.0\text{V}, I_C=0, f=100\text{kHz}$		12		pF
Noise Figure	NF	$I_C=-100\ \mu\text{A}, V_{CE}=-10\text{V}, R_S=-1.0\text{k}\Omega, f=1.0\text{kHz}$		2.0		dB

Note: Pulse Test: Pulse Width  $\leq 300\ \mu\text{s}$ , Duty Cycle  $\leq 2.0\%$

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